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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/699,873	11/04/2003	Masahiro Hatakeyama	2003-1606	5137
513	7590 12/28/2005		EXAMINER	
	TH, LIND & PONACK,	ROSASCO, STEPHEN D		
2033 K STRE			ART UNIT	PAPER NUMBER
	ON, DC 20006-1021		1756	
			DATE MAIL ED: 12/29/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	(,
Office Action Commence	10/699,873	HATAKEYAMA ET AL.	
Office Action Summary	Examiner	Art Unit	
	Stephen Rosasco	1756	
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	correspondence address	
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING D Extensions of time may be available under the provisions of 37 CFR 1.1: after SIX (6) MONTHS from the mailing date of this communication If NO period for reply is specified above, the maximum statutory period v - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tin vill apply and will expire SIX (6) MONTHS from the cause the application to become ABANDONE	N. nely filed the mailing date of this communication D (35 U.S.C. § 133).	
Status			
1) Responsive to communication(s) filed on 14 N	ovember 2005.		
2a) ☐ This action is <b>FINAL</b> . 2b) ☑ This	action is non-final.		
3) Since this application is in condition for allowar	nce except for formal matters, pro	secution as to the merits is	
closed in accordance with the practice under E	Ex parte Quayle, 1935 C.D. 11, 45	53 O.G. 213.	
Disposition of Claims	·		
4) Claim(s) <u>6,10-15 and 29</u> is/are pending in the a	application.		
4a) Of the above claim(s) is/are withdraw	• •		
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>6,10-15 and 29</u> is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/o	r election requirement.		
Application Papers			
9) The specification is objected to by the Examine	r.		
10) The drawing(s) filed on 04 November 2003 is/a		ed to by the Examiner.	
Applicant may not request that any objection to the	· · · · · · · · · · · · · · · · · · ·	•	
Replacement drawing sheet(s) including the correct	•		).
11)☐ The oath or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form PTO-152.	
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119(a)	)-(d) or (f).	
a)⊠ All b)□ Some * c)□ None of:	the second second		
1. Certified copies of the priority documents			
2. Certified copies of the priority documents	• •		
<ol> <li>Copies of the certified copies of the prior</li> <li>application from the International Bureau</li> </ol>		ed in this National Stage	
* See the attached detailed Office action for a list	, ,,	-d	
Attachment(s)			
Notice of References Cited (PTO-892)	4) Interview Summary	(PTO-413)	
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail Da	ate	
B) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 11/04/03.	5)  Notice of Informal P 6)  Other:	atent Application (PTO-152)	

## **Detailed Action**

Applicant's election without traverse of Group I (claims 6, 10-15 and 29) in the reply filed on 10/18/05 is acknowledged.

The disclosure is objected to because of the following informalities: there are numerous spelling and grammatical errors present, e.g., page 2, line 3, "distance of a light source", line 5, "within a subwavelength", line 8, "structures of the structure"; page 4, line 15, "enables to produce"; page 58, lines 1-2, "section of container";

Amend the first sentence of the specification to update the status of the parent application to include that it is now U.S Patent No. 6,671,034.

Appropriate correction is required.

Claims 12 and 15 are rejected under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement. The claim(s) contains subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention. The use of the term fast atomic beam is not described in the specification in such a way that one could use it. What atoms can be used?

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 6 and 29 are rejected under 35 U.S.C. 102(e) as being anticipated by Martin (5,928,815).

Martin teaches the claimed invention (see claims, esp: claim 14).

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 6, 10-15 and 29 are rejected under 35 U.S.C. 103(a) as being unpatentable over Martin (5,928,815).

The claimed invention is directed to a method for evanescent-field-assisted imprinting, comprising: placing a proximity field exposure pattern on a section of container in which light is enclosed; aligning a fabrication object having a photo-sensitive film thereon in proximity of said proximity field exposure pattern; and injecting a light from said container into said proximity field exposure pattern so as to imprint said proximity field exposure pattern on said photo-sensitive material by means of an evanescent field formed between said proximity field exposure pattern and said photo-sensitive film.

The applicant states that the method requires that the incident beam be aligned with the inclination angle of a prism, and the optical system is necessarily complex. Also the exposure pattern section can only accept a small exposure area. And, because the incident light is at an angle to the proximity field exposure pattern, the depth of imprinting is shallow, and because the exposed area increases quickly along the beam line, it is difficult to expose a structure having high aspect ratios on the photo-resist film.

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Martin teaches a near-field optical lithographic mask device for for imaging a desired pattern of light onto a photoresist layer, said mask device comprising:

a) a mask block having a mask end and an illumination end, said illumination end having a flat exterior surface, and

b) a positioning mechanism capable of precisely maintaining said mask in a predetermined vertical position and a predetermined horizontal orientation with respect to said photoresist layer,

and wherein said mask block is approximately cylindrical in shape and made of a material having a high index of refraction and is transparent to ultraviolet light to be used in said imaging and wherein said mask end has imprinted thereon a pattern of ridges and troughs, said ridges replicating said desired pattern, wherein a thin metal film is placed on said mask end, said thin metal film covering all ridges and troughs, wherein said troughs are filled with a light-absorbing material, and wherein said mask block has a metal cladding covering all outside surfaces except for said mask end and said flat exterior surface of said illumination end, wherein said metal cladding is sufficiently thick to reflect all ultraviolet light being transmitted through said mask block.

And wherein said illumination system shines ultraviolet light onto said illumination end of said mask block after said ultraviolet light has passed through a optical-thermal filter.

The teachings of Martin differ from those of the applicant in that the applicant teaches the use of multiple layers on the base substrate. However, the use of multiple layers is known in the art of photolithography and it would have been obvious to one having ordinary skill in the art to take the teachings of Martin and use them with a substrate having multiple layers in order to make the claimed invention because the technique is used to pattern the outermost layer and so the number of layers employed is a function of the specific application required.

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## Conclusion

Any inquiry concerning this communication or earlier communications from the Examiner should be directed to Stephen Rosasco whose telephone number is (571) 272-1389. The Examiner can normally be reached Monday-Friday, from 8:00 AM to 4:30 PM. The Examiner's supervisor, Mark Huff, can be reached on (571) 272-1385. The fax phone number for the organization where this application or proceeding is assigned is (571) 273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

S. Rosasco Primary Examiner

Art Unit 1756

S.Rosasco 12/21/05